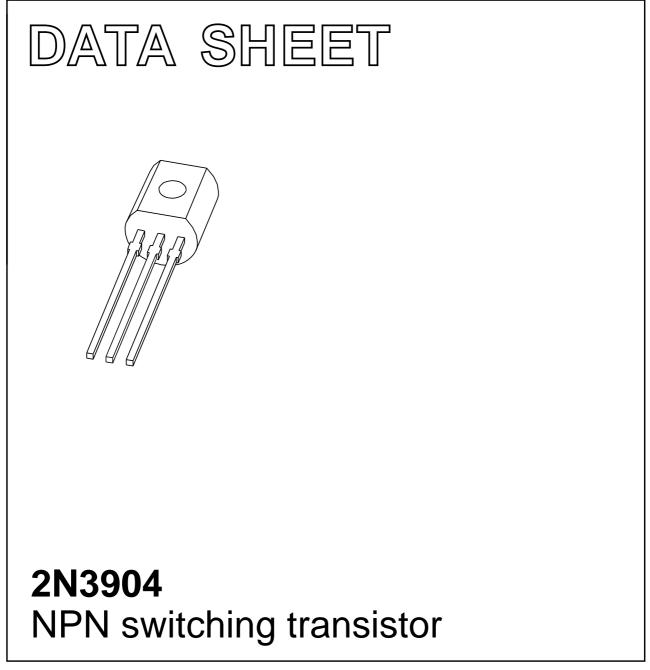
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 23 2004 Oct 11



FEATURES

- Low current (max. 200 mA)
- Low voltage (max. 40 V).

APPLICATIONS

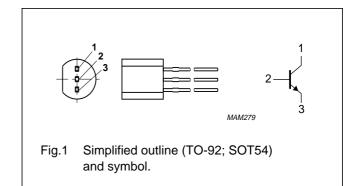
• High-speed switching.

DESCRIPTION

NPN switching transistor in a TO-92; SOT54 plastic package. PNP complement: 2N3906.

PINNING

PIN	DESCRIPTION	
1	collector	
2	base	
3	emitter	



ORDERING INFORMATION

		PACKAGE		
	NAME	DESCRIPTION	VERSION	
2N3904	SC-43A	43A plastic single-ended leaded (through hole) package; 3 leads		

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	60	V
V _{CEO}	collector-emitter voltage	open base	-	40	V
V _{EBO}	emitter-base voltage	open collector	-	6	V
I _C	collector current (DC)		-	200	mA
I _{CM}	peak collector current		-	300	mA
I _{BM}	peak base current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C;$ note 1	-	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

2N3904

2N3904

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

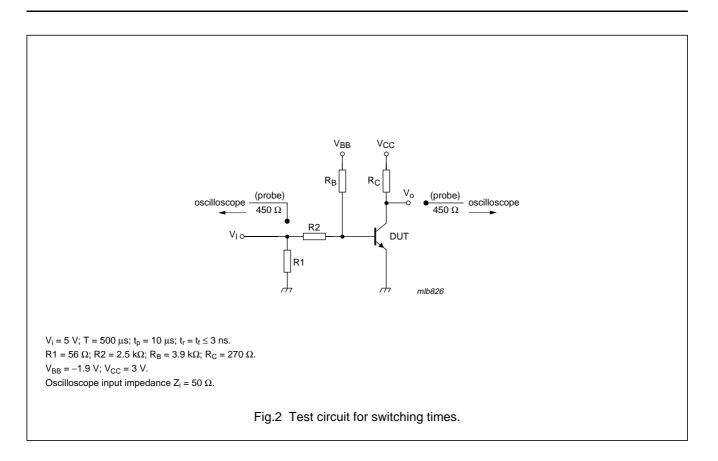
 $T_{amb} = 25 \ ^{\circ}C.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$	-	50	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 6 V; I_{C} = 0 A$	-	50	nA
h _{FE}	DC current gain	V _{CE} = 1 V; note 1			
		$I_{\rm C} = 0.1 {\rm mA}$	60	_	
		$I_{\rm C} = 1 \rm{mA}$	80	-	
		I _C = 10 mA	100	300	
		I _C = 50 mA	60	_	
		I _C = 100 mA	30	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 1 mA; note 1	-	200	mV
		$I_{C} = 50 \text{ mA}; I_{B} = 5 \text{ mA}; \text{ note } 1$	-	200	mV
V _{BEsat}	base-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 1 \text{ mA}; \text{ note } 1$	-	850	mV
		$I_{C} = 50 \text{ mA}; I_{B} = 5 \text{ mA}; \text{ note } 1$	-	950	mV
C _c	collector capacitance	$V_{CB} = 5 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	-	4	pF
C _e	emitter capacitance	$V_{EB} = 500 \text{ mV}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$	-	8	pF
f _T	transition frequency	V _{CE} = 20 V; I _C = 10 mA; f = 100 MHz	300	-	MHz
F	noise figure	V_{CE} = 5 V; I _C = 100 μA; R _S = 1 kΩ; f = 10 Hz to 15.7 kHz	-	5	dB
Switching t	imes (between 10 % and 90 % level	Is); see Fig.2	•	•	
t _{on}	turn-on time	I _{Con} = 10 mA; I _{Bon} = 1 mA;	-	65	ns
t _d	delay time	I _{Boff} = –1 mA	-	35	ns
t _r	rise time	1	_	35	ns
t _{off}	turn-off time	1	_	240	ns
t _s	storage time	1	_	200	ns
t _f	fall time	1	_	50	ns

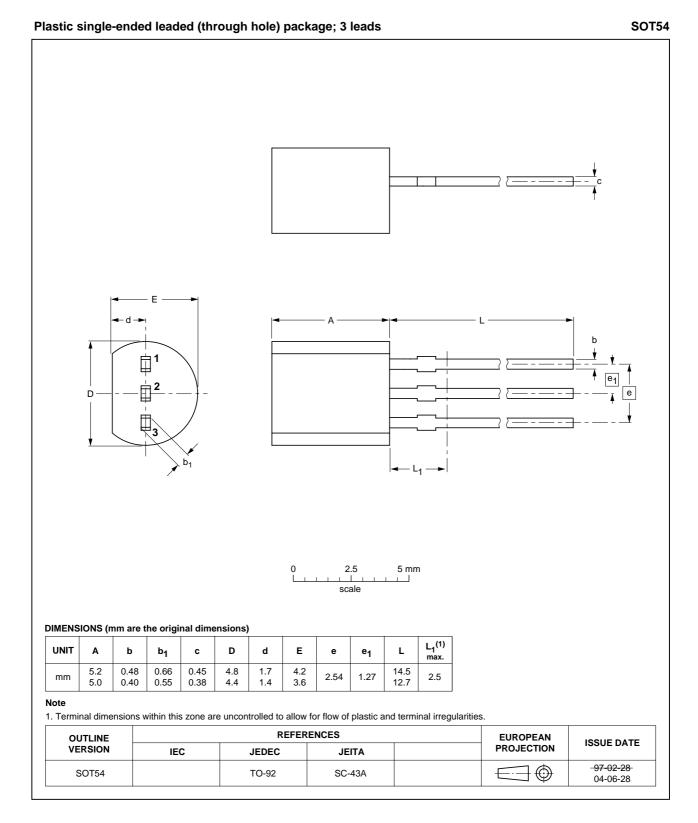
Note

1. Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$.

2N3904



PACKAGE OUTLINE



2N3904

2N3904

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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DEFINITIONS

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Printed in The Netherlands

R75/04/pp7

Date of release: 2004 Oct 11

Document order number: 9397 750 13544

SCA76

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